

LMV358IDR2G Datasheet



DiGi Electronics Part Number

LMV358IDR2G-DG

onsemi

Manufacturer Product Number

Description

Manufacturer

Detailed Description

LMV358IDR2G

CMOS Amplifier 2 Circuit Rail-to-Rail 8-SOIC

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RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
LMV358IDR2G	onsemi
Series:	Product Status:
	Active
Amplifier Type:	Number of Circuits:
CMOS	2
Output Type:	Slew Rate:
Rail-to-Rail	1V/µs
Gain Bandwidth Product:	Current - Input Bias:
1 MHz	1 nA
Voltage - Input Offset:	Current - Supply:
1.7 mV	210μA (x2 Channels)
Current - Output / Channel:	Voltage - Supply Span (Min):
160 mA	2.7 V
Voltage - Supply Span (Max):	Operating Temperature:
5.5 V	-40°C ~ 85°C (TA)
Mounting Type:	Package / Case:
Surface Mount	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package:	
8-SOIC	

Environmental & Export classification

8542.33.0001

RoHS Status:	Moisture Sensitivity Level (MSL):		
ROHS3 Compliant	1 (Unlimited)		
REACH Status:	ECCN:		
REACH Unaffected	EAR99		
HTSUS:			

Single, Dual, Quad Low-Voltage, Rail-to-Rail Operational Amplifiers

LMV321, NCV321, LMV358, LMV324

The LMV321, LMV321I, NCV321, LMV358/LMV358I and LMV324 are CMOS single, dual, and quad low voltage operational amplifiers with rail-to-rail output swing. These amplifiers are a cost-effective solution for applications where low power consumption and space saving packages are critical. Specification tables are provided for operation from power supply voltages at 2.7 V and 5 V. Rail-to-Rail operation provides improved signal-to-noise preformance. Ultra low quiescent current makes this series of amplifiers ideal for portable, battery operated equipment. The common mode input range includes ground making the device useful for low-side current-shunt measurements. The ultra small packages allow for placement on the PCB in close proximity to the signal source thereby reducing noise pickup.

Features

- Operation from 2.7 V to 5.0 V Single–Sided Power Supply
- LMV321 Single Available in Ultra Small 5 Pin SC70 Package
- No Output Crossover Distortion
- Rail-to-Rail Output
- Low Quiescent Current: LMV358 Dual 220 μA, Max per Channel
- No Output Phase-Reversal from Overdriven Input
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

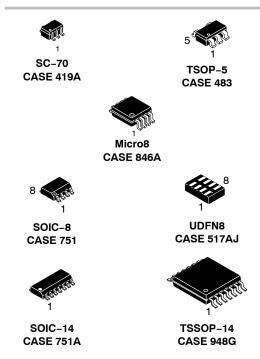
Typical Applications

- Notebook Computers and PDA's
- Portable Battery-Operated Instruments
- Active Filters



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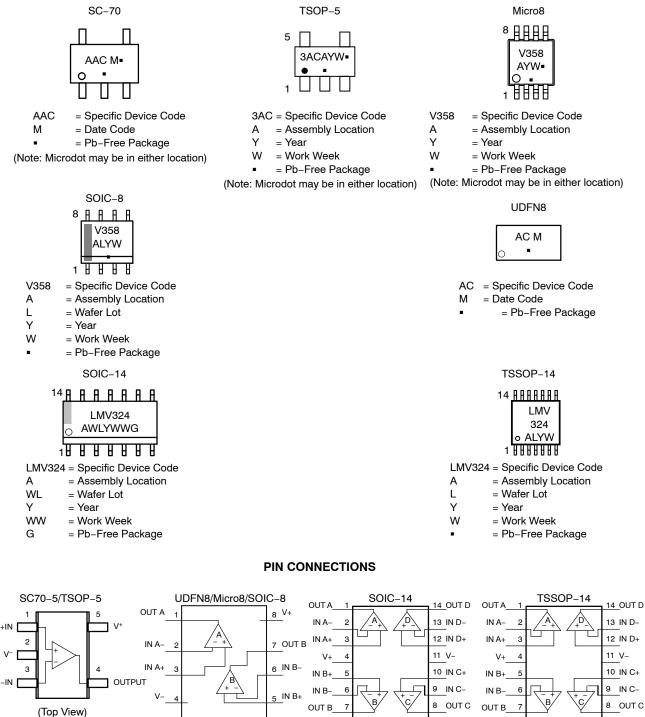


ORDERING AND MARKING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

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(Top View)

(Top View)

(Top View)

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
VS	Supply Voltage (Operating Range V_S = 2.7 V to 5.5 V)	5.5	V
V _{IDR}	Input Differential Voltage	\pm Supply Voltage	V
V _{ICR}	Input Common Mode Voltage Range	-0.5 to (V+) + 0.5	V
	Maximum Input Current	10	mA
t _{So}	Output Short Circuit (Note 1)	Continuous	
ТJ	Maximum Junction Temperature	150	٥°C
T _A	Operating Ambient Temperature Range LMV321, LMV358, LMV324 LMV321I, LMV358I NCV321 (Note 2)	-40 to 85 -40 to 125 -40 to 125	ဂံဂံ
θ_{JA}	Thermal Resistance:		°C/W
	SC-70	280	
	Micro8	238	
	TSOP-5	333	
	UDFN8 (1.2 mm x 1.8 mm x 0.5 mm)	350	
	SOIC-8	212	
	SOIC-14	156	
	TSSOP-14	190	
T _{stg}	Storage Temperature	-65 to 150	°C
	Mounting Temperature (Infrared or Convection -20 sec)	260	°C
V _{ESD}	ESD Tolerance (Note 3) LMV321, LMV321I, NCV321 Machine Model Human Body Model LMV358/358I/324 Machine Model Human Body Mode	100 1000 100 2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

 NCV prefix is qualified for automotive usage.
 Human Body Model, applicable std. MIL-STD-883, Method 3015.7 Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

2.7 V DC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, V⁺ = 2.7 V, $R_L = 1 M\Omega, V^- = 0 V, V_O = V+/2)$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	$T_A = T_{Low}$ to T_{High} (Note 4)		1.7	9	mV
Input Offset Voltage Average Drift	ICV _{OS}	$T_A = T_{Low}$ to T_{High} (Note 4)		5		μV/°C
Input Bias Current	I _B	$T_A = T_{Low}$ to T_{High} (Note 4)		<1		nA
Input Offset Current	I _{IO}	$T_A = T_{Low}$ to T_{High} (Note 4)		<1		nA
Common Mode Rejection Ratio	CMRR	$0 \text{ V} \leq \text{V}_{\text{CM}} \leq 1.7 \text{ V}$	50	63		dB
Power Supply Rejection Ratio	PSRR	$\begin{array}{l} 2.7 \ V \leq V+ \leq 5 \ V, \\ V_O = 1 \ V \end{array}$	50	60		dB
Input Common-Mode Voltage Range	V _{CM}	For CMRR \geq 50 dB	0 to 1.7	–0.2 to 1.9		V
Output Swing	V _{OH}	R_L = 10 k Ω to 1.35 V	V _{CC} – 100	V _{CC} – 10		mV
	V _{OL}	R_L = 10 k Ω to 1.35 V (Note 5)		60	180	mV
Supply Current LMV321, NCV321 LMV358/LMV358I (Both Amplifiers) LMV324 (4 Amplifiers)	I _{CC}			80 140 260	185 340 680	μΑ

2.7 V AC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}$ C, V⁺ = 2.7 V, R_L = 1 MΩ, V^- = 0 V, V_O = V+/2)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gain Bandwidth Product	GBWP	C _L = 200 pF		1		MHz
Phase Margin	Θm			60		0
Gain Margin	G _m			10		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz		50		nV/√Hz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
For LMV321, LMV358, LMV324: T_A = -40°C to +85°C For LMV321I, LMV358I, NCV321: T_A = -40°C to +125°C.
Guaranteed by design and/or characterization.

5.0 V DC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, V⁺ = 5.0 V, $R_L = 1 M\Omega, V^- = 0 V, V_O = V+/2)$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	T _A = T _{Low} to T _{High} (Note 6)		1.7	9	mV
Input Offset Voltage Average Drift	T _C V _{IO}	T _A = T _{Low} to T _{High} (Note 6)		5		μV/°C
Input Bias Current (Note 7)	Ι _Β	T _A = T _{Low} to T _{High} (Note 6)		< 1		nA
Input Offset Current (Note 7)	I _{IO}	T _A = T _{Low} to T _{High} (Note 6)		< 1		nA
Common Mode Rejection Ratio	CMRR	$R \qquad 0 V \le V_{CM} \le 4 V \qquad 50$		65		dB
Power Supply Rejection Ratio	PSRR	$\begin{array}{c} 2.7 \text{ V} \leq \text{V}_{+} \leq 5 \text{ V}, \\ \text{V}_{O} = 1 \text{ V}, \text{V}_{CM} = 1 \text{ V} \end{array} \begin{array}{c} 50 \end{array}$		60		dB
Input Common-Mode Voltage Range	V _{CM}	For CMRR \geq 50 dB	0 to 4	-0.2 to 4.2		V
Large Signal Voltage Gain (Note 7)	A _V	$R_L = 2 k\Omega$	15	100		V/mV
		$T_A = T_{Low}$ to T_{High} (Note 6)	10			
Output Swing	V _{OH}	$\begin{array}{l} R_{L} = 2 \; k\Omega \; \text{to} \; 2.5 \; V \\ T_{A} = T_{Low} \; \text{to} \; T_{High} \; (Note \; 6) \end{array}$	V _{CC} - 300 V _{CC} - 400	V _{CC} - 40		mV
	V _{OL}	$R_L = 2 k\Omega$ to 2.5 V (Note 7) $T_A = T_{Low}$ to T_{High} (Note 6)		120	300 400	mV
	V _{OH}	$ \begin{array}{l} R_L = 10 \ \text{k}\Omega \ \text{to} \ 2.5 \ \text{V} \ (\text{Note 7}) \\ T_A = T_{Low} \ \text{to} \ T_{High} \ (\text{Note 6}) \end{array} $	V _{CC} - 100 V _{CC} - 200			mV
	V _{OL}	R_L = 10 kΩ to 2.5 V T _A = T _{Low} to T _{High} (Note 6)		65	180 280	mV
Output Short Circuit Current	Ι _Ο	Sourcing = $V_0 = 0 V$ (Note 7) Sinking = $V_0 = 5 V$ (Note 7)	10 10	60 160		mA
Supply Current	ICC	LMV321 T _A = T _{Low} to T _{High} (Note 6)		130	250 350	μΑ
		NCV321 T _A = T _{Low} to T _{High} (Note 6)		130	250 350	
		LMV358/358I Both Amplifiers $T_A = T_{Low}$ to T_{High} (Note 6)		210	440 615	
		LMV324 All Four Amplifiers $T_A = T_{Low}$ to T_{High} (Note 6)		410	830 1160	

5.0 V AC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, V⁺ = 5.0 V, R_L = 1 MΩ, V^- = 0 V, V_O = V+/2)

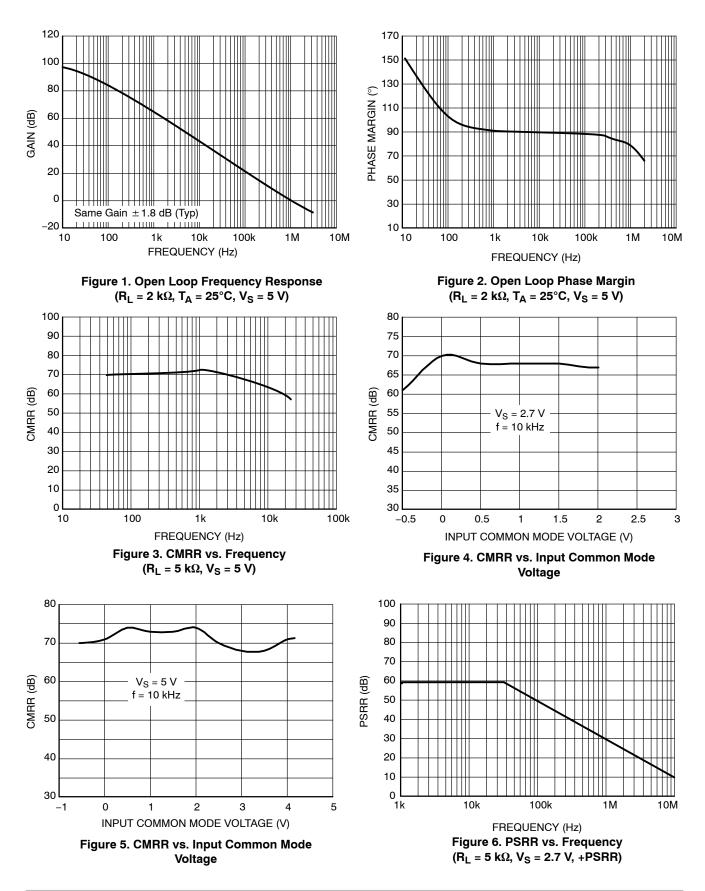
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	S _R			1		V/µs
Gain Bandwidth Product	GBWP	C _L = 200 pF		1		MHz
Phase Margin	Θ _m			60		0
Gain Margin	G _m			10		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz		50		nV/√Hz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics for the listed test conditions. 6. For LMV321, LMV358, LMV324: $T_A = -40^{\circ}C$ to $+85^{\circ}C$ For LMV3211, LMV3581, NCV321: $T_A = -40^{\circ}C$ to $+125^{\circ}C$. 7. Guaranteed by design and/or characterization.

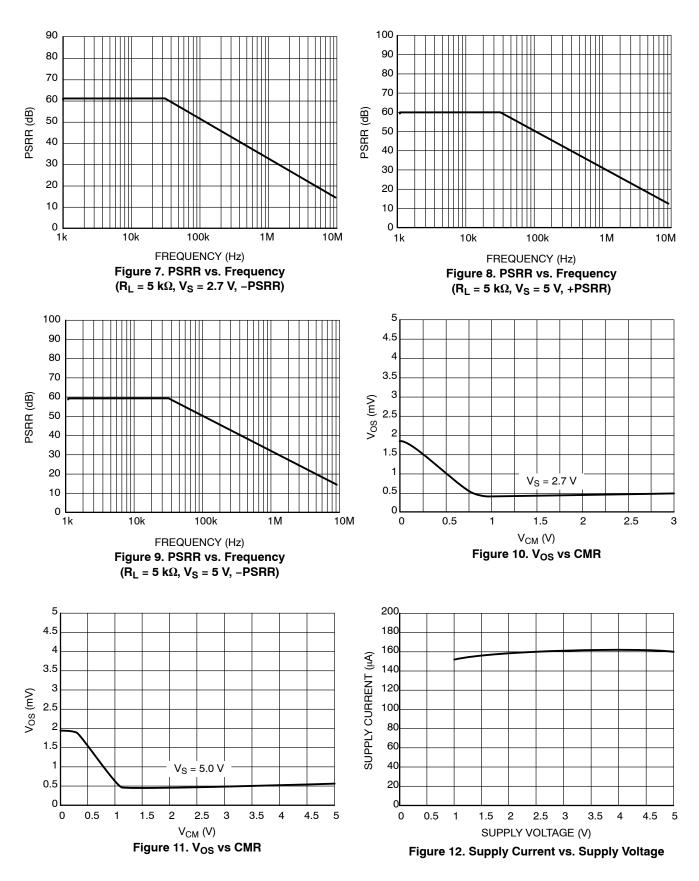
LMV358IDR2G onsemi LV R2R DUAL OP AMP EXTENDED TEMP

LMV321, NCV321, LMV358, LMV324

TYPICAL CHARACTERISTICS



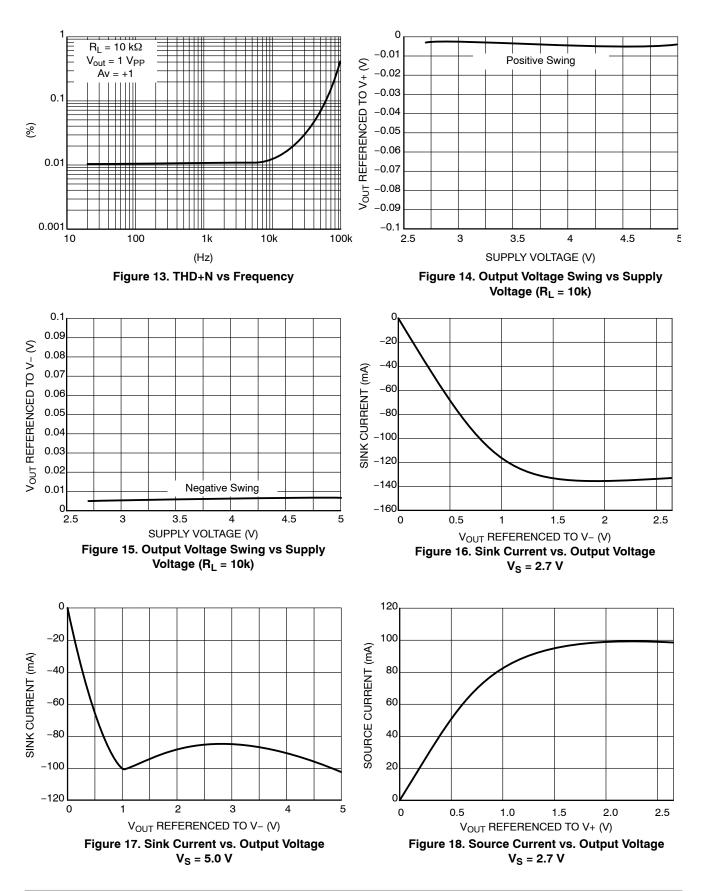
TYPICAL CHARACTERISTICS



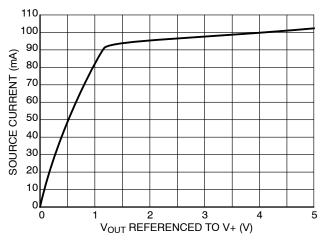
LMV358IDR2G onsemi LV R2R DUAL OP AMP EXTENDED TEMP

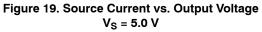
LMV321, NCV321, LMV358, LMV324

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





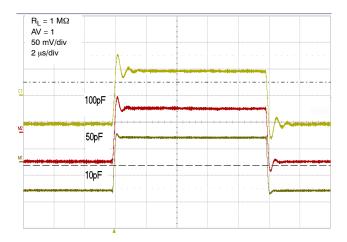


Figure 21. Settling Time vs. Capacitive Load

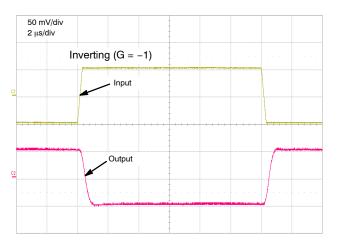


Figure 23. Step Response – Small Signal

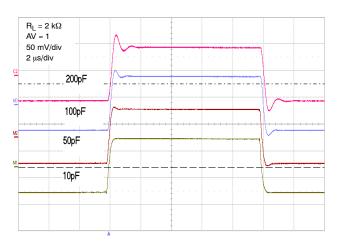


Figure 20. Settling Time vs. Capacitive Load

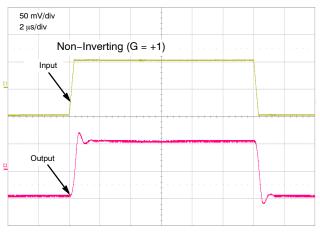
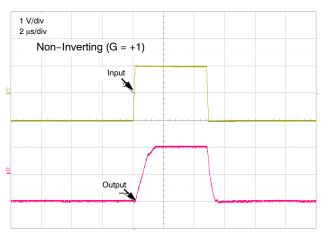


Figure 22. Step Response – Small Signal





LMV358IDR2G onsemi LV R2R DUAL OP AMP EXTENDED TEMP

LMV321, NCV321, LMV358, LMV324

TYPICAL CHARACTERISTICS

(T_A = 25°C and V_S = 5 V unless otherwise specified)

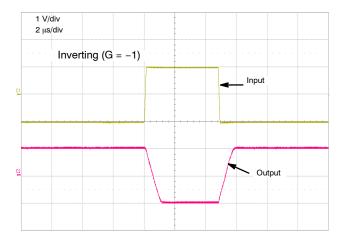
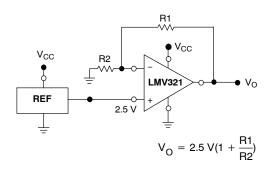
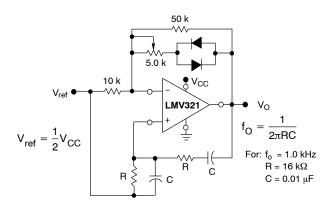


Figure 25. Step Response – Large Signal

APPLICATIONS









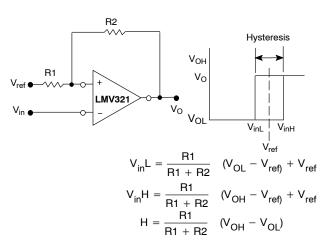
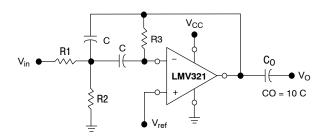
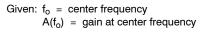


Figure 28. Comparator with Hysteresis





$$\begin{array}{ll} \mbox{Choose value } f_o, C\\ \mbox{Then}: & \mbox{R3} = \frac{Q}{\pi f_O \, C}\\ \mbox{R1} = \frac{R3}{2 \, A(f_O)}\\ \mbox{R2} = \frac{R1 \, R3}{4 Q^2 \, R1 - R3} \end{array}$$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_o and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 29. Multiple Feedback Bandpass Filter

ORDERING INFORMATION

Order Number	Number of Channels	Specific Device Marking	Package Type	Shipping [†]
LMV321SQ3T2G	Single	AAC	SC–70 (Pb–Free)	3000 / Tape & Reel
LMV321SN3T1G	Single	ЗАС	TSOP–5 (Pb–Free)	3000 / Tape & Reel
LMV321ISN3T1G	Single	ЗАС	TSOP-5 (Pb-Free)	3000 / Tape & Reel
NCV321SN3T1G*	Single	ЗАС	TSOP–5 (Pb–Free)	3000 / Tape & Reel
LMV358DMR2G	Dual	V358	Micro8 (Pb–Free)	4000 / Tape & Reel
LMV358MUTAG	Dual	AC	UDFN8 (Pb-Free)	3000 / Tape & Reel
LMV358DR2G	Dual	V358	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LMV358IDR2G	Dual	V358	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LMV324DR2G	Quad	LMV324	SOIC-14 (Pb-Free)	2500 / Tape & Reel
LMV324DTBR2G	Quad	LMV 324	TSSOP-14 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable.



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DATE 11 APR 2023

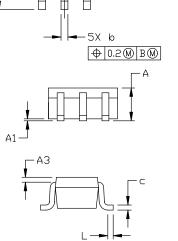
PACKAGE DIMENSIONS



SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

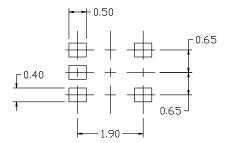
NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE. NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.



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RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
MIU	MIN.	NDM,	MAX,	
А	0.80	0.95	1.10	
A1			0.10	
A3		0.20 REF		
b	0.10	0.20	0,30	
C	0.10		0.25	
D	1.80	2.00	5.20	
E	2.00	2.10	5.20	
E1	1.15	1.25	1.35	
e	0.65 BSC			
L	0.10	0.15	0.30	

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

M = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

DESCRIPTION:	SC-88A (SC-70-		ns are uncontrolled except w	viten stamped CONTROLLED	PAGE 1 OF 1
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED	
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style t out in the datasheet i datasheet pinout or p	ype is not called refer to the device
STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	DE

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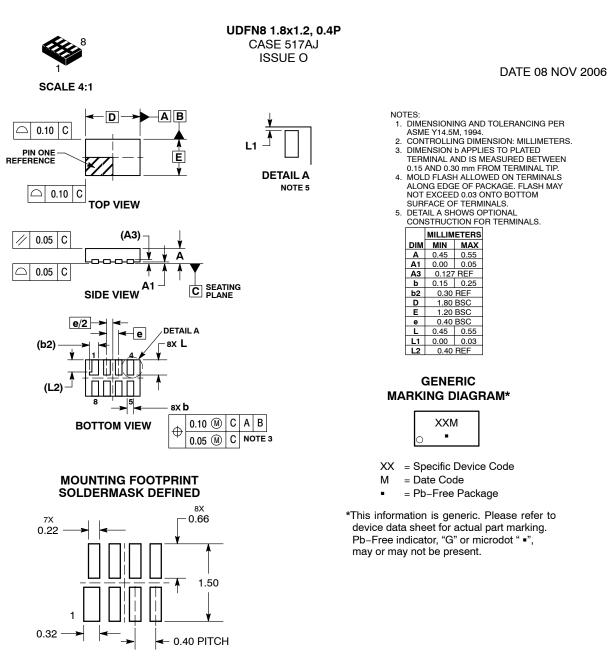
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

TSOP-5 3.00x1.50x0.95, 0.95P **CASE 483** ISSUE P DATE 01 APR 2024 NOTES: 5X b 0.20 C A B DIMENSIONING AND TOLERANCING CONFORM TO ASME NOTE 5 1. Y14.5-2018. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES). MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. 2. В 3. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. E1 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION D. 5 OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS PIN 1 ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND IDENTIFIER le MORE THAN 0.2 FROM BODY. A MILLIMETERS DIM NOM. TOP VIEW MIN. MAX. 0.900 1.000 1.100 DETAIL A А (A2) A1 0.010 0.055 0.100 Α2 0.950 REF 0.250 0.375 0.500 h 0.100 0.180 0.260 0.05 C с SEATING 2.850 3.150 D 3.000 Ċ A1 PLANE END VIEW SIDE VIEW Е 2.500 2.750 3.000 1.350 E1 1.500 1.650 0.950 BSC е 0.250 GAUGE 0.400 L 0.200 0.600 0° 5° 10° Θ 1.900Ð 0.950 "A DETAIL SCALE 2:1 GENERIC **MARKING DIAGRAM*** 2.400 5 5 XXXAYW-XXX M= 1.000 1 0.700Analog Discrete/Logic RECOMMENDED MOUNTING FOOTPRINT* XXX = Specific Device Code XXX = Specific Device Code FOR ADDITIONAL INFORMATION ON OUR Pb-FREE А = Assembly Location Μ = Date Code STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD = Pb-Free Package v = Year THE ON SEMICONDUCTOR SOLDERING AND MOUNTING W = Work Week TECHNIQUES REFERENCE MANUAL, SOLDERRM/D. = Pb-Free Package (Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "∎", may or may not be present. Some products may not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98ARB18753C **DESCRIPTION:** TSOP-5 3.00x1.50x0.95, 0.95P PAGE 1 OF 1 onsemi and OnSemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



DIMENSIONS: MILLIMETERS

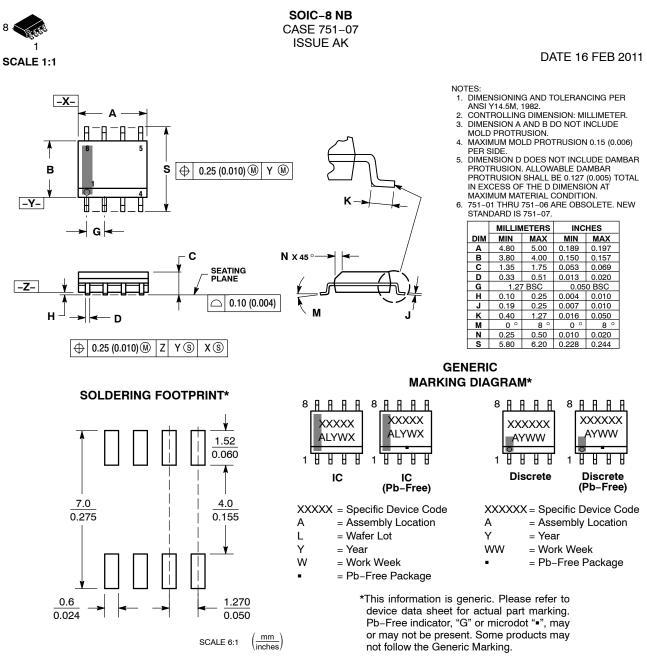
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4 FMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. 5. GATE 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE, DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17 PIN 1. VCC 2. V2OUT V10UT 3. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: CATHODE 1 PIN 1. 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C З. REXT 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE. #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2

STYLE 2: COLLECTOR, DIE, #1 PIN 1. COLLECTOR, #1 2. COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER. #1 8. STYLE 6: SOURCE PIN 1. 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: N-SOURCE PIN 1. 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18 PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8 VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: DRAIN, DIE #1 PIN 1. DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. 5. GATE, #2 SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS З. THIRD STAGE SOURCE GROUND 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3 ANODE 1 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1 STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 З. UVLO 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: PIN 1. ANODE ANODE 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: 1. SW_TO_GND 2. DASIC OFF PIN 1. DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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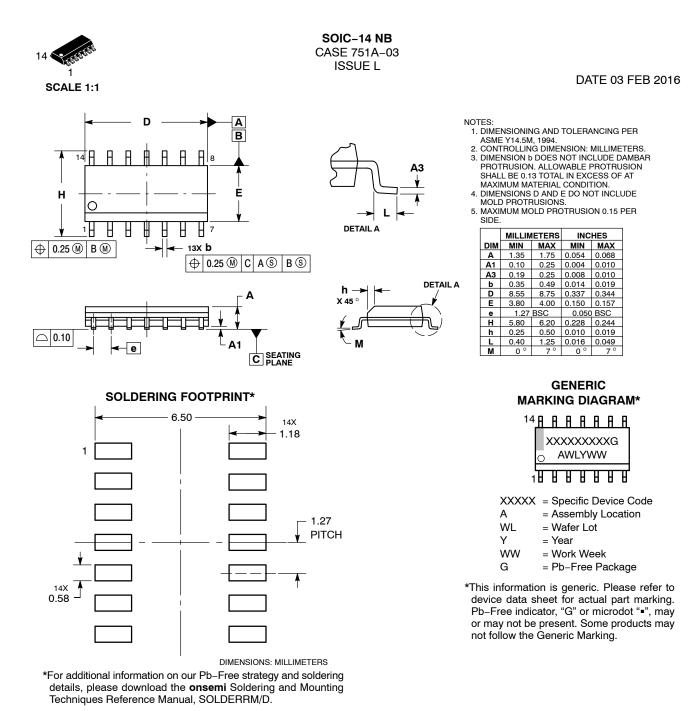
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COLLECTOR, #1

COLLECTOR, #1





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SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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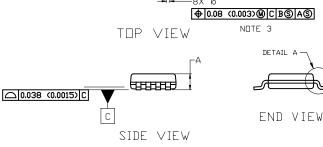
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SCALE 2:1

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

Micro8 CASE 846A-02 ISSUE K DATE 16 JUL 2020 NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009. В 2. CONTROLLING DIMENSION: MILLIMETERS AAAA DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSION 4. Δ1 OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DETAIL A DIMENSIONS D AND E ARE DETERMINED AT DATUM F. -8X b ⊕0.08 (0.003) @CBS AS 5. DATUMS A AND B ARE TO BE DETERMINED AT DATUM F. NDTE 3 A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE 6. SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY. DETAIL A -A



GENERIC

MARKING DIAGRAM*

8 8 8 8 8 8 XXXX AYW-

8888

= Work Week = Pb-Free Package

= Year

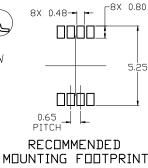
not follow the Generic Marking.

= Specific Device Code = Assembly Location

XXXX

А Υ

W



DIM	MILLIMETERS		
DIM	MIN.	NDM.	MAX.
A			1.10
A1	0.05	0.08	0.15
ю	0.25	0.33	0.40
с	0.13	0.18	0.23
D	2.90	3.00	3.10
E	2.90	3.00	3.10
e	0.65 BSC		
HE	4.75	4.90	5.05
L	0.40	0.55	0.70

= Pb-Free Package			
v	STYLE 1:	STYLE 2:	STYLE 3:
(Note: Microdot may be in either location)	PIN 1. SOURCE	PIN 1. SOURCE 1	PIN 1. N-SOURCE
	2. SOURCE	2. GATE 1	2. N-GATE
*This information is generic. Please refer to	3. SOURCE	SOURCE 2	P-SOURCE
device data sheet for actual part marking.	4. GATE	4. GATE 2	4. P-GATE
1 0	5. DRAIN	5. DRAIN 2	5. P-DRAIN
Pb–Free indicator, "G" or microdot "∎", may	6. DRAIN	6. DRAIN 2	6. P-DRAIN
or may not be present. Some products may	7. DRAIN	7. DRAIN 1	7. N-DRAIN
not follow the Conoria Marking	8. DRAIN	8. DRAIN 1	8. N-DRAIN

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